

Switchmode Dual Fast Recovery Power Rectifiers

... Designed for use in switching power supplies. inverters and as free wheeling diodes. These state-of-the-art devices have the following features:

- * Glass Passivated chip junctions
- * Low Reverse Leakage Current
- * Fast Switching for High Efficiency
- * 150 °C Operating Junction Temperature
- * Low Forward Voltage , High Current Capability
 * Plastic Material used Carries Underwriters Laboratory Flammability Classification 94V-O

*In compliance with EU RoHs directives



MAXIMUM RATINGS

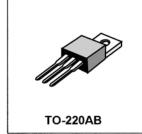
Characteristic	Symbol	F06C			Unit	
		05	10	15	20	
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _R	50	100	150	200	V
RMS Reverse Voltage	V _{R(RMS)}	35	70	105	140	V
Average Rectifier Forward Current Per Leg T _c =125°C Per Total Device	I _{F(AV)}	3.0 6.0			А	
Peak Repetitive Forward Current (Rate V _R ,Square Wave,20kHz,T _c =125°C)	I _{FM}	6.0		Α		
Non-Repetitive Peak Surge Current (Surge applied at rate load conditions halfware,single phase,60Hz)	I _{FSM}	50		Α		
Operating and Storage Junction Temperature Range	T _j , T _{stg}		- 65 to	+ 150		°C

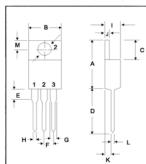
ELECTRICAL CHARACTERISTICS

Characteristic	Symbol	F06C				Unit
		05	10	15	20]
Maximum Instantaneous Forward Voltage (I _F =3.0 Amp, T _c = 25 °C)	V _F	1.30			V	
Maximum Instantaneous Reverse Current (Rated DC Voltage, $T_c = 25$ °C) (Rated DC Voltage, $T_c = 125$ °C)	I _R	5.0 70			uA	
Reverse Recovery Time (I _F = 0.5 A, I _R =1.0 , I _{rr} =0.25 A)					ns	
Typical Junction Capacitance (Reverse Voltage of 4 volts & f=1 MHz)	C _P	55			pF	

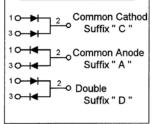
FAST RECOVERY RECTIFIERS

6.0 AMPERES 50 -- 200 VOLTS





DIM	MILLIM	MILLIMETERS			
ואוט	MIN	MAX			
Α	14.68	16.00			
В	9.78	10.42			
С	5.02	6.60			
D	13.00	14.62			
E	3.10	4.19			
F	2.41	2.67			
G	1.10	1.67			
Н	0.69	1.01			
ı	3.21	4.98			
J	1.14	1.40			
K	2.20	3.30			
L	0.28	0.61			
M	2.48	3.00			
0	3.50	4.00			



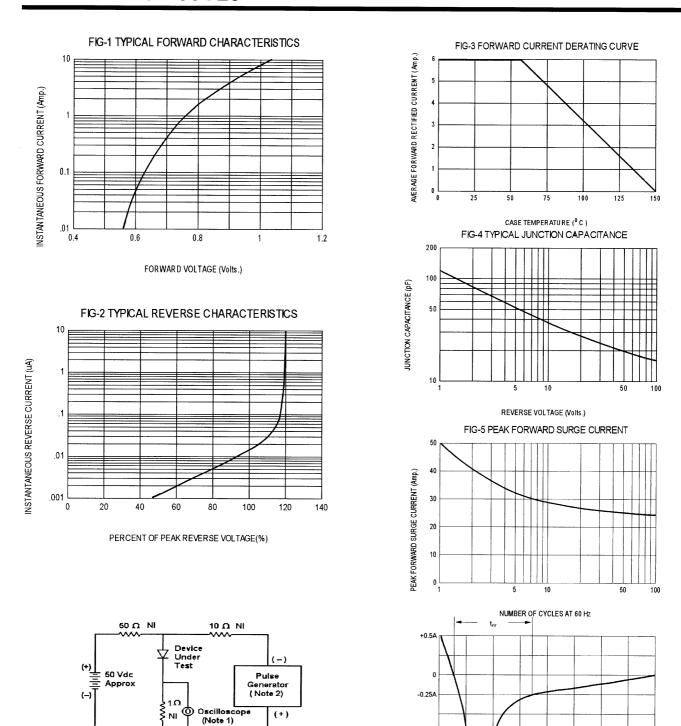


Fig-6 Reverse Recovery Time Characteristic and Test Circuit Diagram

-1 0A

Set time base for 50 ns/div

Notes: 1. Rise Time = 7 ns max. Input Impedance =1 M Ω , 22 pF 2. Rise Time = 10 ns max. Input Impedance = 50 Ω



Notice

MOSPEC reserves the rights to make changes of the content herein the document anytime without notification. MOSPEC or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies. Please refer to MOSPEC website for the last document.

MOSPEC disclaims any and all liability arising out of the application or use of any product including damages incidentally and consequentially incurred.

Application shown on the herein document are examples of standard use and operation. Customers are responsible for comprehending suitable use in particular applications. MOSPEC makes no representation or warranty that such application will be suitable for the specified use without further testing or modification.

The information contained herein is presented only as a guide for the applications of our products. No responsibility is assumed by MOSPEC for any infringements of patents or other rights of the third parties which may result from its use. No license is granted by implication or otherwise under any patent or patent rights of MOSPEC or others.

These MOSPEC products are intended for usage in general electronic equipment. Please make sure to consult with MOSPEC before you use these MOSPEC products in equipment which require specialized quality and/or reliability, and in equipment which could have major impact to the welfare of human life (atomic energy control, aeronautics, traffic control, combustion control, safety devices etc.)